

# MUR160 - MUR190



# 1.0 AMPS. Glass Passivated High Efficient Rectifiers DO-15/DO-204AC

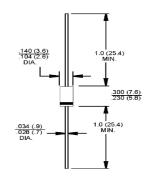


## **Features**

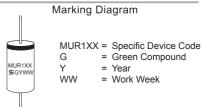
- Designed for use in switching power supplies, inverters and as free wheeling diodes
- ♦ High efficiency, low VF
- ♦ High reliability
- Ultrafast recovery time for high efficiency
- ♦ 175°C operating junction temperature
- Green compound with suffix "G" on packing code & marking
- Green compound with suffix "G" on packing code & prefix "G" on datecode.

## **Mechanical Data**

- ♦ Cases: Molded plastic
- ♦ Epoxy: UL 94V-0 rate flame retardant
- Lead: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- ♦ Polarity: Color band denotes cathode
- High temperature soldering guaranteed: 260 °C /10 seconds/ 375",(9.5mm) lead lengths at 5 lbs.,(2.3kg) tension
  - Weight: 0.34 grams



## Dimensions in inches and (millimeters)



## **Maximum Ratings and Electrical Characteristics**

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%

Type Number	Symbol	MUR160	MUR190	Units
Maximum Recurrent Peak Reverse Voltage	VRRM	600	900	V
Maximum RMS Voltage	VRMS	420	630	V
Maximum DC Blocking Voltage	VDC	600	900	V
Maximum Average Forward Rectified Current (Square Wave Note 4) @ T <sub>A</sub> =80 °C	I(AV)	1.0		А
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	IFSM	35		А
Maximum Instantaneous Forward Voltage @ 1.0A Tj=150°C Tj=25°C	VF	1.05 1.25	1.5 1.7	V
Maximum DC Reverse Current @ $T_A$ =25 °C at Rated DC Blocking Voltage @ $T_A$ =125 °C	lR	5.0 150		uA uA
Maximum Reverse Recovery Time (Note 2)	Trr	50	75	nS
Typical Junction Capacitance ( Note 1 )	Cj	27	15	pF
Typical Thermal Resistance (Note 3)	Reja	50		°C/W
Operating Temperature Range	TJ	-65 to +175		°C
Storage Temperature Range	Tstg	-65 to +175		°C

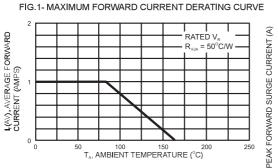
Notes:

- 1. Measured at 1 MHz and Applied Reverse Voltage of 4.0 Volts D.C.
- 2. Reverse Recovery Test Conditions: I<sub>F</sub>=0.5A, I<sub>R</sub>=1.0A, I<sub>RR</sub>=0.25A
- 3. Thermal Resistance from Junction to Ambient, with units Mounted on P.C. Board with 0.4" x 0.4" Copper Surface.
- 4. Pulse Test: Pulse Width = 300uS, Duty Cycle ≤2.0%.

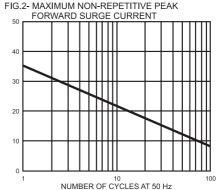
Version: D08

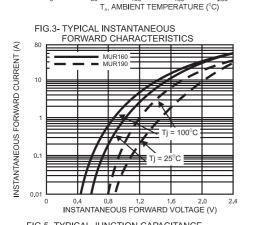


#### RATINGS AND CHARACTERISTIC CURVES (MUR160 THRU MUR190)



150

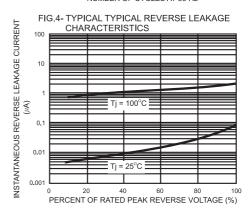


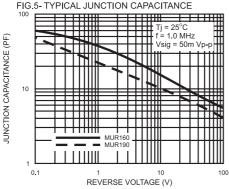


100

0

0





#### FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

